Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	
Glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.107 inches	
Joint Electronic D	Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Method	:
Terminal	
Features Provide	d:
Hermetically seale	d case
Semiconductor M	aterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
200.0 reverse volt	age, peak
Current Rating Pe	er Characteristic:
40.00 milliamperes	forward current, average absolute
Maximum Operati	ing Tempurature Per Measurement Point:
150.0 degrees cels	sius ambient air
Test Data Docum	ent:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes of	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type An	d Quantity:
2 uninsulated wire	lead
Specification Data	a:
81349-mil-s-19500	/193 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	